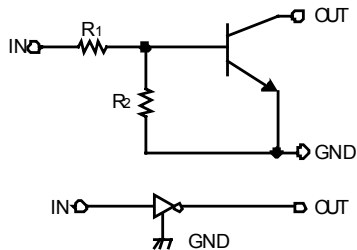


NPN DIGITAL TRANSISTOR (BUILT-IN RESISTORS)

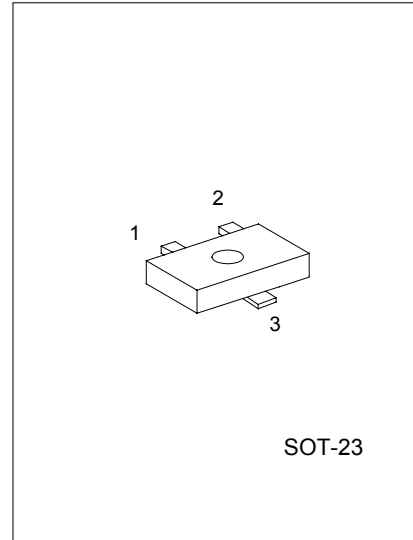
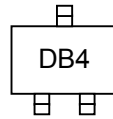
FEATURES

- *Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see the equivalent circuit).
- *The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- *Only the on / off conditions need to be set for operation, making device design easy.

EQUIVALENT CIRCUIT



MARKING



1: GND 2: IN 3: OUT

ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V _{CC}	50	V
Input Voltage	V _{IN}	-10~+40	V
Output Current	I _C	500	mA
Power Dissipation	P _D	200	mW
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55 ~ +150	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	V _{I(off)}	V _{CC} =5V, I _O = 100 μA			0.5	V
	V _{I(ON)}	V _O =0.3V, I _O = 10mA	3			
Output Voltage	V _{O(ON)}	I _O /I _I = 50mA/2.5 mA		0.1	0.3	V
Input Current	I _I	V _I =5V			0.88	mA
Output Current	I _{O(off)}	V _{CC} =50V, V _I =0V			0.5	μA
DC Current Gain	G _I	V _O =5V, I _O = 50mA	56			
Input Resistance	R _I		7	10	13	kΩ
Resistance Ratio	R ₂ /R ₁		0.8	1	1.2	
Transition Frequency	f _T	V _{CE} = 10 V, I _E =-50mA, f=100MHz *		200		MHz

*Transition frequency of the device

ELECTRICAL CHARACTERISTIC CURVES

